

## Excellent Integrated System Limited

Stocking Distributor

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[IXYS Corporation](#)  
[VUO28-12NO7](#)

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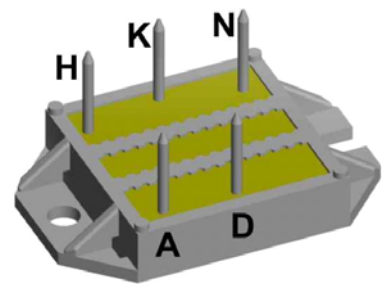
## Standard Rectifier Module


<b>3~ Rectifier</b>	
$V_{RRM}$	= 1200 V
$I_{DAV}$	= 30 A
$I_{FSM}$	= 120 A

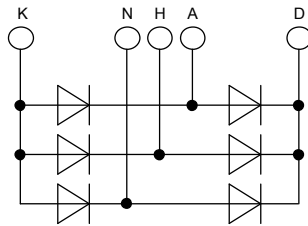
### 3~ Rectifier Bridge

Part number

**VUO28-12N07**



 E72873



#### Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

#### Applications:

- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

#### Package: ECO-PAC1

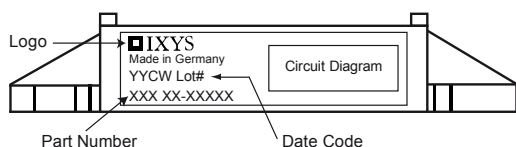
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Height: 9 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Rectifier				Ratings			Unit
Symbol	Definition	Conditions	min.	typ.	max.		
$V_{RSM}$	max. non-repetitive reverse blocking voltage				1300	V	
$V_{RRM}$	max. repetitive reverse blocking voltage				1200	V	
$I_R$	reverse current	$V_R = 1200\text{ V}$	$T_{VJ} = 25^\circ\text{C}$		10	$\mu\text{A}$	
		$V_R = 1200\text{ V}$	$T_{VJ} = 150^\circ\text{C}$		0.7	mA	
$V_F$	forward voltage drop	$I_F = 10\text{ A}$	$T_{VJ} = 25^\circ\text{C}$		1.20	V	
					1.61	V	
		$I_F = 30\text{ A}$	$T_{VJ} = 125^\circ\text{C}$		1.14	V	
					1.68	V	
$I_{DAV}$	bridge output current	$T_C = 105^\circ\text{C}$ rectangular $d = \frac{1}{3}$	$T_{VJ} = 150^\circ\text{C}$		30	A	
$V_{F0}$	threshold voltage	} for power loss calculation only	$T_{VJ} = 150^\circ\text{C}$		0.84	V	
$r_F$	slope resistance				28.8	m $\Omega$	
$R_{thJC}$	thermal resistance junction to case				2.5	K/W	
$R_{thCH}$	thermal resistance case to heatsink			0.4		K/W	
$P_{tot}$	total power dissipation		$T_C = 25^\circ\text{C}$		50	W	
$I_{FSM}$	max. forward surge current	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$	$T_{VJ} = 45^\circ\text{C}$		120	A	
					130	A	
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$	$V_R = 0\text{ V}$	$T_{VJ} = 150^\circ\text{C}$		100	A
						110	A
$I^2t$	value for fusing	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$	$T_{VJ} = 45^\circ\text{C}$		72	A <sup>2</sup> s	
					70	A <sup>2</sup> s	
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$	$V_R = 0\text{ V}$	$T_{VJ} = 150^\circ\text{C}$		50	A <sup>2</sup> s
						50	A <sup>2</sup> s
$C_J$	junction capacitance	$V_R = 400\text{ V}; f = 1\text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$	4		pF	



# VUO28-12NO7

Package ECO-PAC1		Ratings				
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			100	A
$T_{stg}$	storage temperature		-40		125	°C
$T_{vj}$	virtual junction temperature		-40		150	°C
<b>Weight</b>				19		g
$M_D$	mounting torque		1.5		2	Nm
$d_{Spp/App}$	creepage distance on surface   striking distance through air	terminal to terminal	6.0			mm
$d_{Spb/Apb}$		terminal to backside	10.0			mm
$V_{ISOL}$	isolation voltage	t = 1 second	3000			V
		t = 1 minute	2500			V

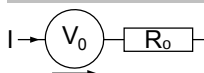


Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	VUO28-12NO7	VUO28-12NO7	Box	25	479632

## Equivalent Circuits for Simulation

\* on die level

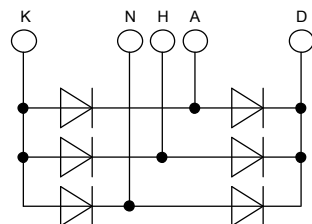
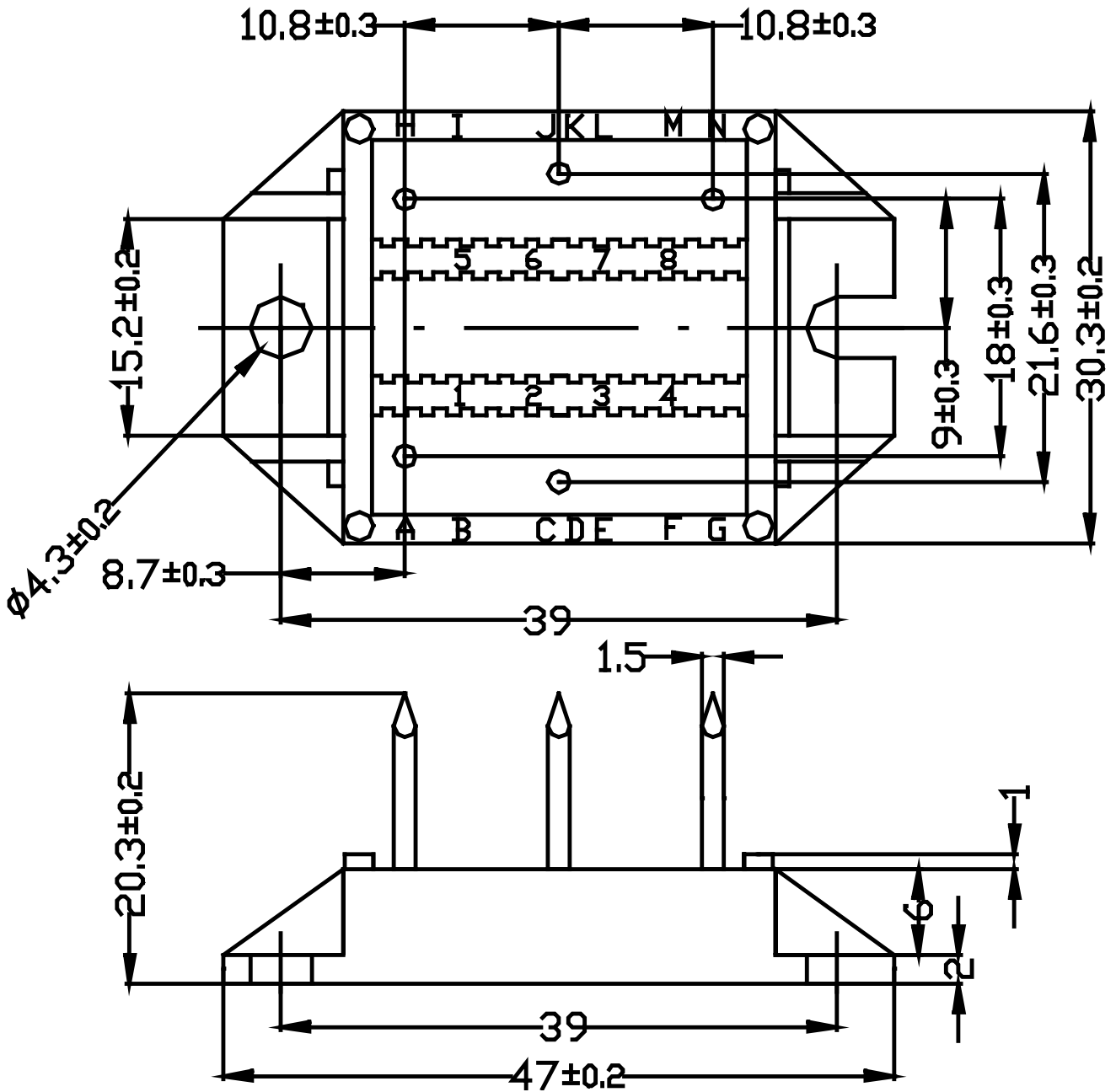
$T_{vj} = 150^\circ\text{C}$



Rectifier

$V_{0\max}$	threshold voltage	0.84	V
$R_{0\max}$	slope resistance *	27.6	mΩ

Outlines ECO-PAC1



**Rectifier**

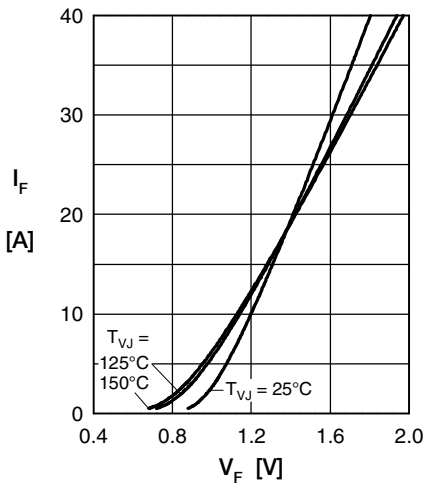


Fig. 1 Forward current vs. voltage drop per diode

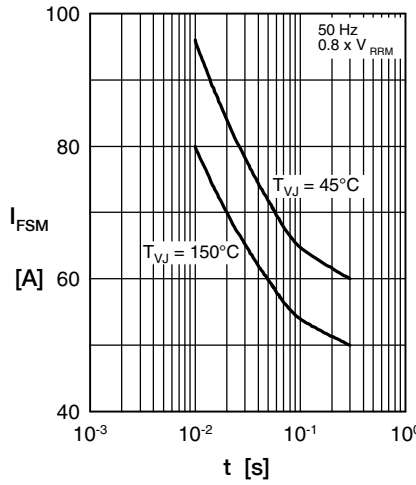


Fig. 2 Surge overload current vs. time per diode

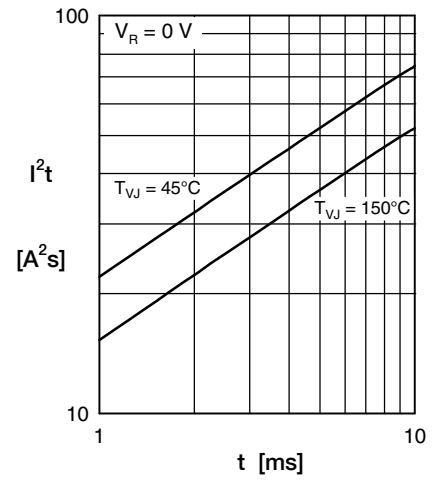


Fig. 3 I<sup>2</sup>t vs. time per diode

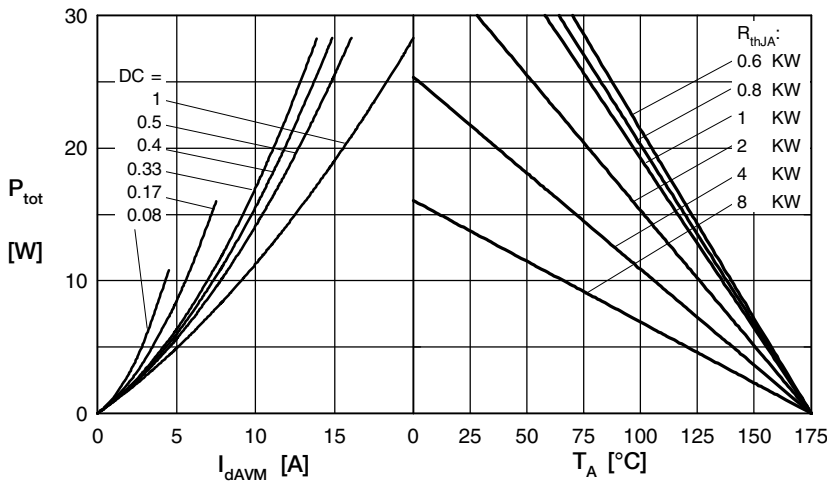


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

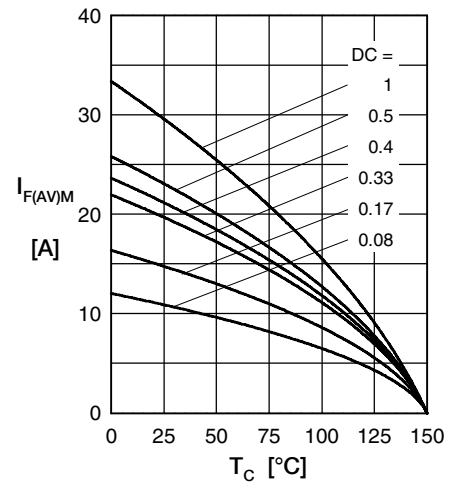


Fig. 5 Max. forward current vs. case temperature per diode

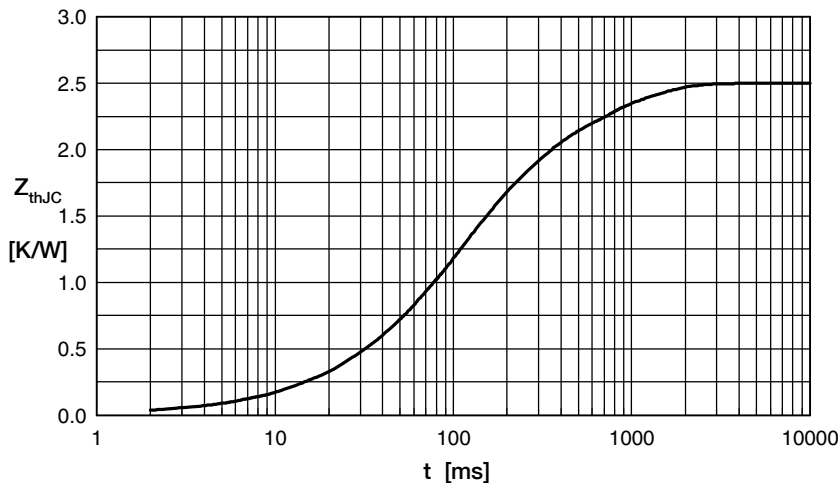


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for  $Z_{thJC}$  calculation:

i	$R_{th}$ (K/W)	$t_i$ (s)
1	1.359	0.1015
2	0.3286	0.1026
3	0.1651	0.4919
4	0.6473	0.62